## NSN 5962-01-226-4345

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inch	es and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power D	issipation Rating:
794.0 milliwatts	
Operating Tempur	ature Range:
-55.0/+125.0 degree	s celsius
Storage Tempurate	ire Range:
-65.0/+150.0 degree	s celsius
End Application:	
An/bps14to15e	
Features Provided	
Hermetically sealed	and burn in and programmable and bipolar and schottky
Inclosure Material:	
Ceramic	
Inclosure Configur	ation:
Dual-in-line	
Output Logic Form	:
Transistor-transistor	logic
Input Circuit Patte	n:
10 input	
Case Outline Sour	ce And Designator:
D-2 mil-m-38510	
Terminal Surface 1	reatment:
Solder	
Voltage Rating An	I Type Per Characteristic:
-0.5 volts power so	Irce and 7.0 volts power source
Time Rating Per C	nacteristic:
85.00 nanoseconds	propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	be:
Prom	
Memory Capacity:	
Unknown	
Test Data Docume	nt:
96906-mil-std-883 s	andard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	Quantity:
16 printed circuit	
Shelf Life:	
N/a	

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

